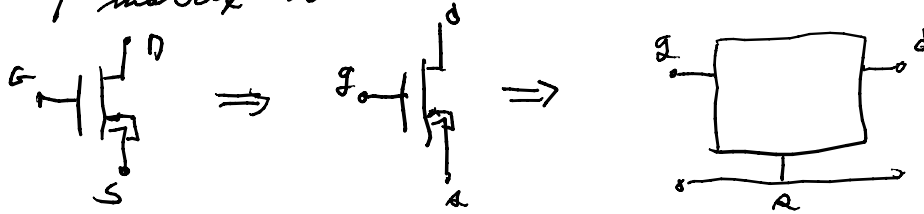
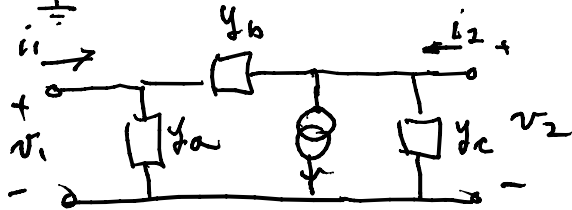


Small signal equivalent circuits

Y matrix used:

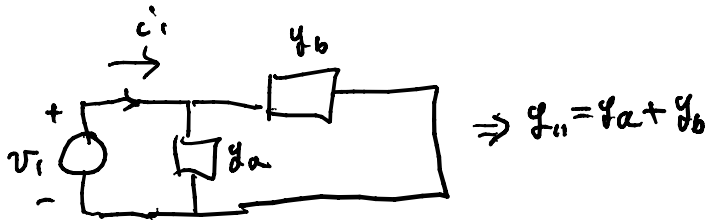


Linear circuit model:
$$\begin{bmatrix} i_1 \\ i_2 \end{bmatrix} = \begin{bmatrix} y_{11} & y_{12} \\ y_{21} & y_{22} \end{bmatrix} \begin{bmatrix} v_1 \\ v_2 \end{bmatrix} \Rightarrow i = Yv$$



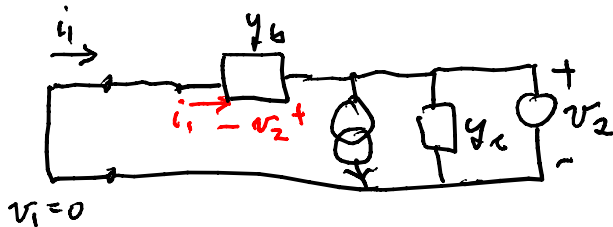
$$y_{11} = \left. \frac{i_1}{v_1} \right|_{v_2=0}$$

= short on "port" 2



$$y_{12} = \left. \frac{i_1}{v_2} \right|_{v_1=0}$$

= short on port 1

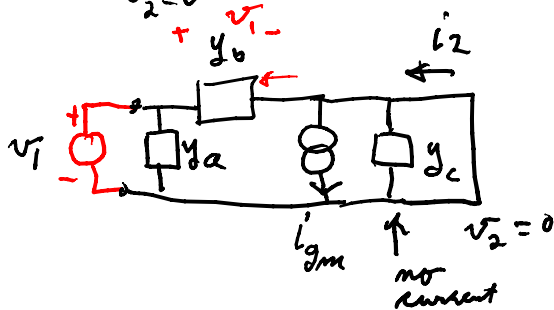


here $i_1 = -y_b v_2 \Rightarrow y_{12} = -y_b$

$$y_{11} = y_a - y_{12} \Rightarrow y_a = y_{11} + y_{12}$$

$$y_{21} = \left. \frac{i_2}{v_1} \right|_{v_2=0}$$

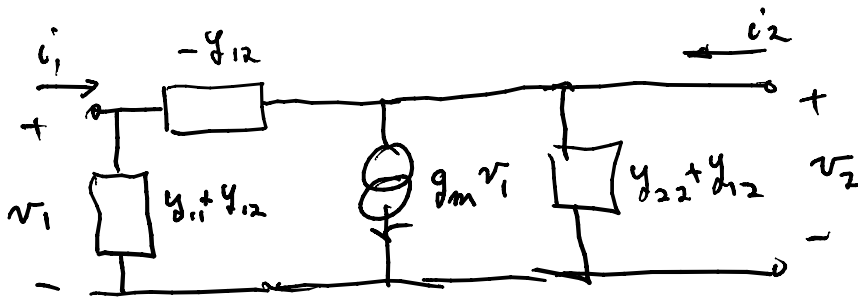
$$y_{22} = \left. \frac{i_2}{v_2} \right|_{v_1=0}$$



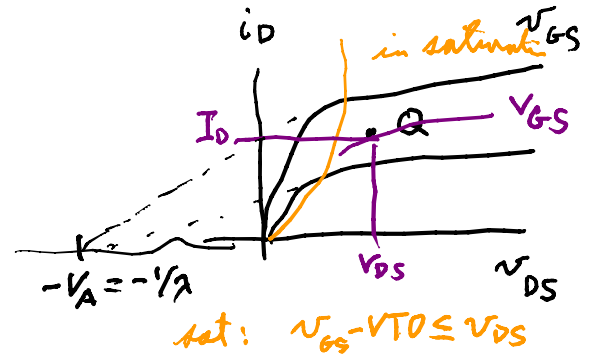
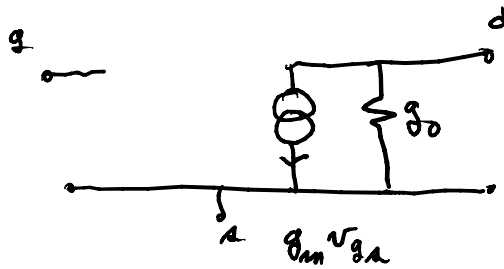
here $i_2 = i_{gm} + (-y_b v_1) \Rightarrow y_{21} = \left. \frac{i_2}{v_1} \right|_{v_2=0} = \frac{i_{gm}}{v_1} - y_b$

$$= \frac{i_{gm}}{v_1} + y_{12}$$

$$\Rightarrow \frac{i_{gm}}{v_1} = y_{21} - y_{12} \triangleq g_m \text{ (= def. of } g_m)$$



this is the TT equivalent circuit for a linear 2-port



$$g_m = 2 \frac{I_D}{(V_{GS} - V_{T0})}$$

$$g_o = \frac{I_D}{V_A} \times \frac{1}{1 + v_{ds}/V_A}$$

$$Y = \begin{bmatrix} 0 & 0 \\ g_m & g_o \end{bmatrix}$$

$$i_D = \frac{K_P W}{2 L} (V_{GS} - V_{T0})^2 (1 + \lambda V_{DS})$$

Ex: $\left\{ \begin{array}{l} K_P = 2 \times 10^{-4} \frac{\text{ampere}}{\text{volt}^2} \\ B-S \end{array} \right.$ transistor properties

$W = 10\mu$, $L = 10\mu$, $V_{T0} = 1.1 \text{ volt}$, $V_A = 200 \text{ volt}$

circuit choice: Q $V_{GS} = 3.1 \text{ V}$, $V_{DS} = 3 \text{ V}$

check on transistor status: $V_{GS} - V_{T0} = 2 \text{ V} < V_{DS} = 3$

$$I_D = \frac{2 \times 10^{-4}}{2} \cdot \frac{10 \times 10^{-6}}{10 \times 10^{-6}} (2)^2 \left(1 + \frac{3}{200}\right) \approx 4 \times 10^{-4} \text{ ampere} = 0.4 \text{ mA}$$

thus at Q: $g_m = \frac{2 I_D}{(V_{GS} - V_{T0})} = \frac{2 \times 4 \times 10^{-4}}{2} = 0.4 \text{ mS}$

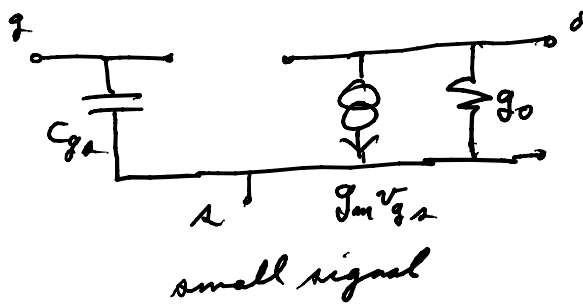
$$r_o = \frac{1}{g_o} = \frac{V_A}{I_D} = \frac{200}{4 \times 10^{-4}} = 50 \times 10^4 = 500 \text{ k}\Omega$$

For higher frequencies we need to add the capacitances
total gate capacitance is $W \times L \times \frac{\epsilon_{ox}}{t_{ox}}$; $\approx 2.43 \epsilon_{ox} = 3.45 \times 10^{-11} \frac{\text{Farad}}{\text{meter}}$

"Useful" capacitance: in saturation: $C_{gs} = \frac{2}{3} \cdot W \times L \times C_{ox}$
r. 821

$$C_{gd} = 0$$

in ohmic: $C_{gs} = C_{gd} = \frac{1}{2} W \times L \times C_{ox}$



$$Y(s) = \begin{bmatrix} C_{gs} \cdot s & 0 \\ g_m & g_o \end{bmatrix}$$